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NTE1368 Integrated Circuit Dual Audio Power Amplifier, 5.8W/Channel

Description:

The NTE1368 is an integrated circuit in a 12-Lead SIP type package designed for dual, low-frequency, high power amplifier applications. This device requires few external components, thus enabling high density mounting. Design for heat radiation is easy due to low thermal resistance. The NTE1368 contains internal power-on pop noise protection circuitry and various other protection circuits. This device is best suited for car stereo applications.

Features:

- High Power Output
- Low Noise Output Voltage
- Low Total Harmonic Distortion
- Minimum External Components
- On-Chip Power On Pop Noise Protection Circuit
- Audio Mute Function is provided
- Separated GND Pins for Input/Output Circuit
- Various Protection Circuits:
 - Overvoltage Protection
 - Thermal Protection
 - Load Short Protection
 - Output Pin-to-DC Short Protection

Absolute Maximum Ratings: (Note 1)

Power Supply Voltage, V_{CC}	
No Signal	24V
Operational	18V
Surge ($t_s \leq 0.2$ sec, $t_r \geq 1$ msec)	40V
Output Current (Peak), I_{OPEAK}	4.5A
Power Dissipation, P_D	18W
Operating Case Temperature Range, T_C	-20° to +75°C
Storage Temperature Range, T_{stg}	-55° to +150°C

Note 1. Permanent device damage may occur if "ABSOLUTE MAXIMUM RATINGS" are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating condition for extended periods may affect device reliability.

Recommended Operating Conditions:

Power Supply Voltage, V_{CC}	8 to 16V
Operating Temperature Range, T_C	-20° to +75°C
Output Load (Dual Operation), R_L	2Ω to 8Ω

Electrical Characteristic: ($V_{CC} = 13.2V$, $f = 1kHz$, $R_L = 4\Omega$, $T_C = +25^\circ C$, One Channel Operation unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Quiescent Power Supply Current	I_Q	$V_{IN} = 0V$, $R_L = \infty$	–	80	160	mA
Voltage Gain	A_V	$P_O = 1W$	48.5	50.5	52.5	dB
Difference Voltage Gain	ΔA_V	$P_O = 1W$	–	0	1.5	dB
Output Power	P_O	THD = 10%	5.0	5.8	–	W
Total Harmonic Distortion	THD	$P_O = 1W$	–	0.2	1.0	%
Output Noise Voltage	V_{NO}	$R_g = 10k\Omega$, BW = 20 to 20kHz	–	0.8	1.6	mV
Input Resistance	R_{In}		20	30	–	k Ω
Cross Talk	CT	$R_g = 600\Omega$	40	50	–	dB
Audio Mute Attenuation		$R_g = 600\Omega$	–	40	–	dB

Pin Connection Diagram
(Front View)

